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May 2024

# **FAN73932** Half-Bridge Gate Drive IC

#### **Features**

- Floating Channel for Bootstrap Operation to +600V
- Typically 2.5A/2.5A Sourcing/Sinking Current Driving Capability
- Extended Allowable Negative V<sub>S</sub> Swing to -9.8V for Signal Propagation at V<sub>BS</sub>=15V
- High-Side Output in Phase of IN Input Signal
- 3.3V and 5V Input Logic Compatible
- Matched Propagation Delay for Both Channels
- Built-in Shutdown Function
- Built-in UVLO Functions for Both Channels
- Built-in Common-Mode dv/dt Noise Canceling Cir ...
- Internal 400ns Minimum Dead-Time

### **Applications**

- High-Speed Power M SFET and
- Induction Heating
- High-Power /C-DC Co.
- CE IS NOTE: I ■ Synchronus Jup-D vn Converter

### Description

The FAN73932 is a half-bridge, gate drive IC with shutdown and dead-time functions and drive highspeed MOSFETs and IGBTs that perate o to +600V it has a buffered output of ye with "I NN JS transisions designed for high bulk or and doing capability and minimum cross-col ctic

p. Less and common-mode Fairchild's h. -volta noise can line echni les provide stable operation of h-sic dr. unde high dv/dt noise circumranced level-shift circuit offers high-side a er operation up to  $\frac{1}{2}$  =-3.8V (typical) for  $V_{BS}$  5V.

The UVLO circuit preven a malfunction when VDD and V<sub>B</sub>, are lower than the specified threshold voltage.

The high current and lov-cutput voltage drop feature makes this device suitable for all kinds of half- and fullbridge inverters, like motor drive inverter, switching noce power supply, induction heating, and high-power DC-DC converter applications.

8-SOP



## Ordering Information

Part Number	Package	Operating Temperature Range	© Eco Status	Packing Method
FAN73932M	8-SOP	-40°C to +125°C	40°C to +125°C RoHS	
FAN73932MX	8-30F	-40 C to +125 C	Kuris	Tape & Reel



For Fairchild's definition of Eco Status, please visit: http://www.fairchildsemi.com/company/green/rohs green.html.

# **Typical Application Diagrams**

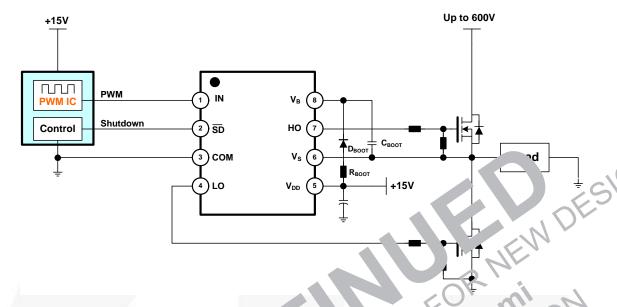


Figure 1. Ty - Applic tion Circuit

# Internal Block Di gram

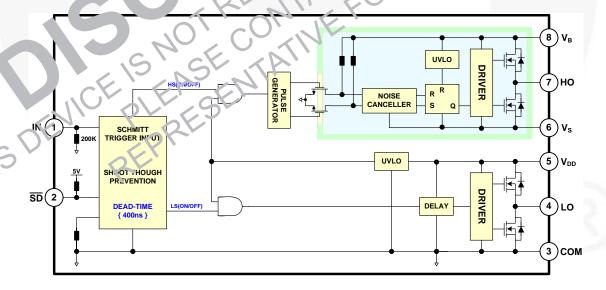


Figure 2. Functional Block Diagram

# **Pin Configuration**

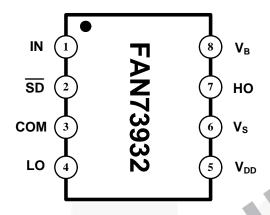


Figure 3. Pin Configuration (Too V v)

### **Pin Definitions**

Pin #	Name	escription
1	IN	Logic Input to High-Solar and Low-Side Gate Driver Output, In Phase with HO
2	SD	Logic i for utdow
3	COM	1 NE OU OF
4	LO	Low-S D. er Return
5	) DD	Supply Voltage
6	V <sub>S</sub>	Hign-Voltage Floating איניבו Return
7		High-Side Driver Cutput
8	$V_{B}$	r ligh-Side Floating Supply

### **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.  $T_A=25^{\circ}C$  unless otherwise specified.

Symbol	Parameter	Min.	Max.	Unit
V <sub>B</sub>	High-Side Floating Supply Voltage	-0.3	625.0	V
V <sub>S</sub>	High-Side Floating Offset Voltage	V <sub>B</sub> -25.0	V <sub>B</sub> +0.3	V
V <sub>HO</sub>	High-Side Floating Output Voltage	V <sub>S</sub> -0.3	V <sub>B</sub> +0.3	V
V <sub>LO</sub>	Low-Side Output Voltage	-0.3	V <sub>DD</sub> +0.3	V
V <sub>DD</sub>	Low-Side and Logic Fixed Supply Voltage	-0.3	25	V
V <sub>IN</sub>	Logic Input Voltage (IN)	-0.3	V <sub>L</sub> +0.3	V
V <sub>SD</sub>	Logic Input Voltage (SD)	-0.3	5.	X 3
COM	Logic Ground and Low-Side Driver Return	V <sub>D.</sub> 25.	V <sub>Dr</sub> +0.3	
dV <sub>S</sub> /dt	Allowable Offset Voltage Slew Rate		± 50	V/ns
P <sub>D</sub>	Power Dissipation <sup>(1, 2, 3)</sup>		0.625	W
$\theta_{JA}$	Thermal Resistance		200	°C/W
TJ	Junction Temperature	7 6	+150	°C
T <sub>STG</sub>	Storage Temperature	-55	150	O <sub>°</sub> C

#### Notes:

- 2. Refer to the following standar 5.
  - JESD51-2: Integral circuis thermal test method environmental conditions natural convection;
- 3. Do not exceed P Inder any circumstances.

## Recominended / perating Conditions

Recommended on the conditions table defines the conditions for actual device operation. Recommended on the conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommended them on designing to absolute maximum ratings.

Symbol	Parameter	Min.	Max.	Unit
,\F	High-Side Floating Supply Voltage	V <sub>S</sub> +10	V <sub>S</sub> +20	V
C V <sub>S</sub>	High-Side Floating Supply Offset Voltage	6-V <sub>DD</sub>	600	V
V <sub>HO</sub>	Higi -Side Output Voltage	V <sub>S</sub>	$V_{B}$	V
$V_{DD}$	Low-Side and Logic Fixed Supply Voltage	10	20	V
$V_{LO}$	Low-Side Output Voltage	COM	$V_{DD}$	V
V <sub>IN</sub>	Logic Input Voltage (IN)	COM	$V_{DD}$	V
$V_{SD}$	Logic Input Voltage (SD)(4)	COM	5	V
T <sub>A</sub>	Operating Ambient Temperature	-40	+125	°C

#### Note:

4. Shutdown (SD) input is internally clamped with 5.2V.

### **Electrical Characteristics**

 $V_{BIAS}(V_{DD},\ V_{BS})$ =15.0V, COM=0V, and  $T_A$  = 25°C, unless otherwise specified. The  $V_{IN}$  and  $I_{IN}$  parameters are referenced to COM and are applicable to the respective input leads: IN and  $\overline{SD}$ . The  $V_O$  and  $I_O$  parameters are referenced to COM and are applicable to the respective output leads: HO and LO.

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
POWER S	SUPPLY SECTION			•	•	
$I_{QDD}$	Quiescent V <sub>DD</sub> Supply Current	V <sub>IN</sub> =0V, SD=5V		320	700	μΑ
I <sub>QBS</sub>	Quiescent V <sub>BS</sub> Supply Current	V <sub>IN</sub> =0V or 5V, SD=5V		50	120	μΑ
I <sub>PDD</sub>	Operating V <sub>DD</sub> Supply Current	f <sub>IN</sub> =20KHz, No Load, SD=5V		700	1300	μА
I <sub>PBS</sub>	Operating V <sub>BS</sub> Supply Current	C <sub>L</sub> =1nF, f <sub>IN</sub> =20KHz, rms, SD=5V		42	800	μА
I <sub>SD</sub>	Shutdown mode Supply Current	SD=0V, SD=5V		40	800	μΔ
I <sub>LK</sub>	Offset Supply Leakage Current	V <sub>B</sub> =V <sub>S</sub> =600V			10	μА
BOOTST	RAPPED SUPPLY SECTION				1	1
V <sub>DDUV+</sub> V <sub>BSUV+</sub>	V <sub>DD</sub> and V <sub>BS</sub> Supply Under-Voltage Positive Going Threshold Voltage	V <sub>Dr</sub> -V <sub>BS</sub> = vet	8	9	10	V
V <sub>DDUV-</sub> V <sub>BSUV-</sub>	V <sub>DD</sub> and V <sub>BS</sub> Supply Under-Voltage Negative Going Threshold Voltage	\ =\ =Sweep	7.4	ა.4	Q.i	V
V <sub>DDUVH</sub> - V <sub>BSUVH</sub>	V <sub>DD</sub> and V <sub>BS</sub> Supply Under-Voltage ackout Hysteresis Voltage	V <sub>DD</sub> =V <sub>BS</sub> =Sw <sup>-</sup> ;en	2	0.6		V
INPUT LC	OGIC SECTION	CALLE	214			
V <sub>IH</sub>	Logic "1" Input Voltag or HC LC 5 "0" for LC	100.00	2.5			V
$V_{IL}$	Logic "0" Input Valtag for HO Logic "1" for LO	14 191			8.0	V
$I_{IN+}$	Logic Input Igh Bias Cu	\(\sigma_{IN}=5\), \(\overline{SD} = 0\)\(\sigma_{IN}=0)\)		25	60	μΑ
I <sub>IN-</sub>	Loc' put L v Biar Current	V <sub>IN</sub> =CV. SD =5V			3	μΑ
R <sub>IN</sub>	Lc Pull-Down Pesistance			200		ΚΩ
V <sub>S</sub> r · <sub>IP</sub>	hutd าพก เปิ้) Innul Clamping Voltage	S. C.		5.0	5.5	V
SD+	S. 'down (SD) input Positive-Coing Threshold		2.5			V
<u>D</u> -	Shutdo vn (SD) input Negative-Guing Threshold	2			0.8	V
R <sub>F</sub>	Shudown (SD) Input Pull-บอ Kesistance			200		ΚΩ
GATE OF	NVER OUTPUT SECTION					
V <sub>OH</sub>	High-level Output Voltage (V <sub>BIAS</sub> - V <sub>O</sub> )	No Load			1.5	V
V <sub>OL</sub>	Low-level Output Voltage	No Load			100	mV
I <sub>O+</sub>	Output High, Short-Circuit Pulsed Current <sup>(5)</sup>	V <sub>HO</sub> =0V, V <sub>IN</sub> =5V, PW ≤10μs	2.0	2.5		Α
I <sub>O-</sub>	Output Low, Short-Circuit Pulsed Current <sup>(5)</sup>	V <sub>HO</sub> =15V,V <sub>IN</sub> =0V, PW ≤10μs	2.0	2.5		Α
Vs	Allowable Negative $V_S$ Pin Voltage for IN Signal Propagation to HO			-9.8	-7.0	V

### Note:

5 These parameters guaranteed by design.

# **Dynamic Electrical Characteristics**

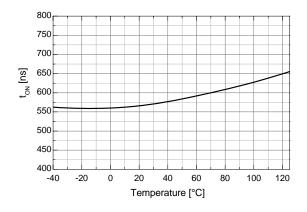
 $\label{eq:Vblass} V_{BIAS}(V_{DD},\,V_{BS}) = 15.0V,\,COM = 0V,\,C_L = 1000pF,\,and\,T_A = 25^{\circ}C,\,unless\,\,otherwise\,\,specified.$ 

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
t <sub>ON</sub>	Turn-On Propagation Delay Time <sup>(6)</sup>	V <sub>S</sub> =0V		600	850	ns
t <sub>OFF</sub>	Turn-Off Propagation Delay Time	V <sub>S</sub> =0V		200	350	ns
t <sub>SD</sub>	Shutdown Propagation Delay Time			140	220	ns
Mt <sub>ON</sub>	Delay Matching, HO and LO Turn-On			0	50	ns
Mt <sub>OFF</sub>	Delay Matching, HO and LO Turn-Off			0	50	ns
t <sub>R</sub>	Turn-On Rise Time	V <sub>S</sub> =0V		25	50	ns
t <sub>F</sub>	Turn-Off Fall Time	V <sub>S</sub> =0V			35	ns
DT	Dead-Time: LO Turn-Off to HO Turn-On and HO Turn-Off to LO Turn-On		2)	100	00	ทธ
MDT	Dead-time matching= DT <sub>LO-HO</sub> - DT <sub>HO-LO</sub>			L	50	หรั

#### Note:

6. The turn-on propagation delay time included dead-time.

## **Typical Characteristics**



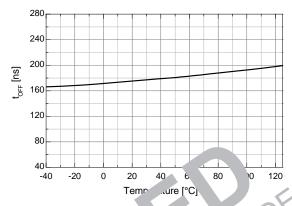
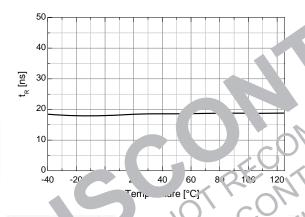


Figure 4. Turn-On Propagation Delay vs. Temperature

Figure 5. rn- Pror jation Delay



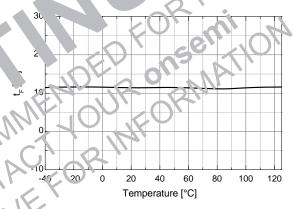
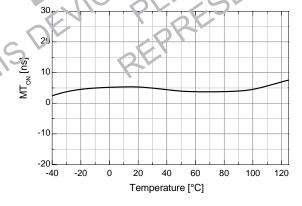


Figure 7. Turn-Off Fall Time vs. Temperature



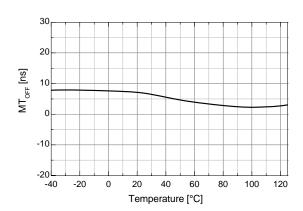
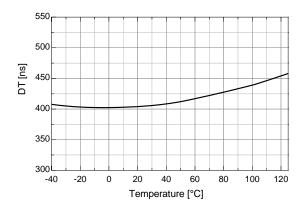


Figure 8. Turn-On Delay Matching vs. Temperature

Figure 9. Turn-Off Delay Matching vs. Temperature

## Typical Characteristics (Continued)



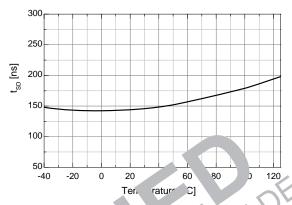
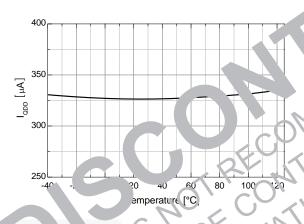


Figure 10. Dead-Time vs. Temperature

Figur 11. Sh. low opagation Delay vs. emperature



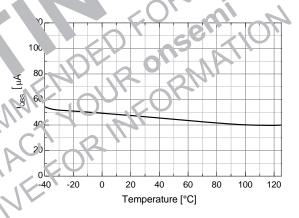
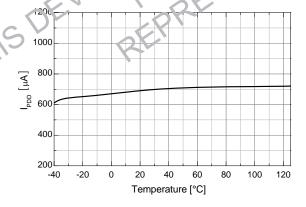


Fig e 1 Quiescent V<sub>DD</sub> Supply Current vs. Temperature

Figure 13. Quiescent V<sub>BS</sub> Supply Current vs. Temperature



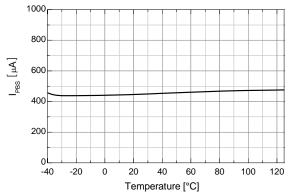
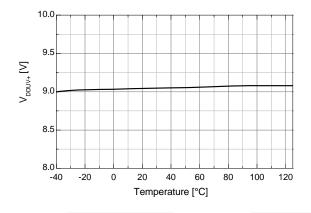


Figure 14. Operating V<sub>DD</sub> Supply Current vs. Temperature

Figure 15. Operating V<sub>BS</sub> Supply Current vs. Temperature

## Typical Characteristics (Continued)



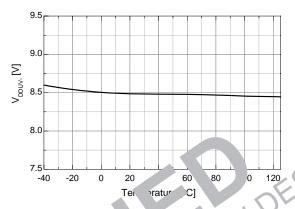
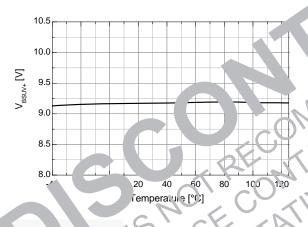


Figure 16. V<sub>DD</sub> UVLO+ vs. Temperature

Figu. 17. V<sub>L</sub> UV. vs. Temperature



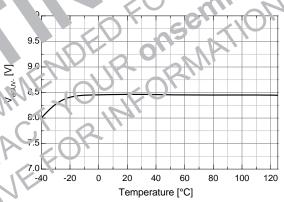
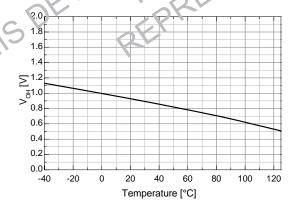


Fig. re . d. V<sub>FS</sub> UVLO+ vs. Temperature

Figure 19. V<sub>BS</sub> UVLO- vs. Temperature



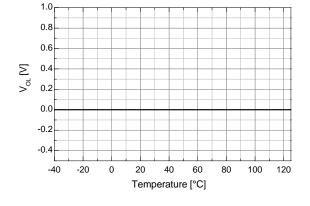
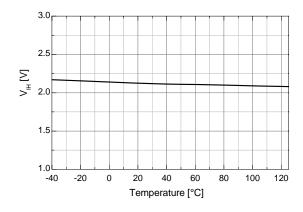


Figure 20. High-Level Output Voltage vs. Temperature

Figure 21. Low-Level Output Voltage vs. Temperature

## Typical Characteristics (Continued)



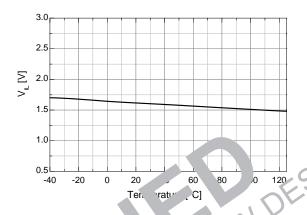
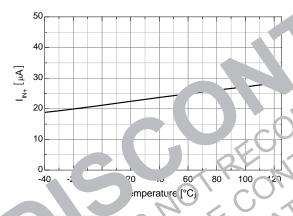


Figure 22. Logic High Input Voltage vs. Temperature

Fig 9 23. gic / Inpv:/ Valtage vs. emperature



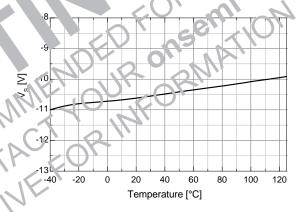


Fig. re. Logic liput High Sias Current
vs. Temperature

Figure 25. Allowable Negative V<sub>S</sub> Voltage vs. Temperature

# **Switching Time Definitions**

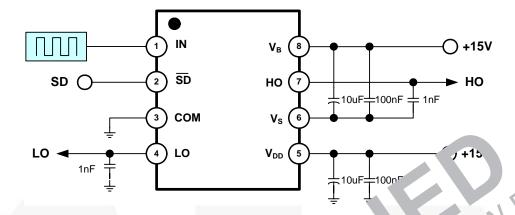


Figure 26. Switching Time Tex Circ it

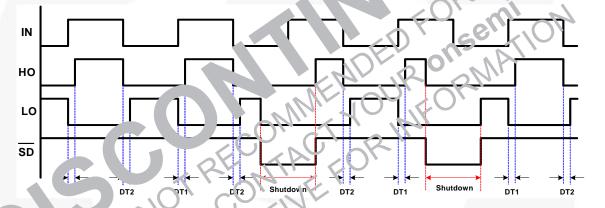


Figure 27. Input/Cutput Timing Diagram

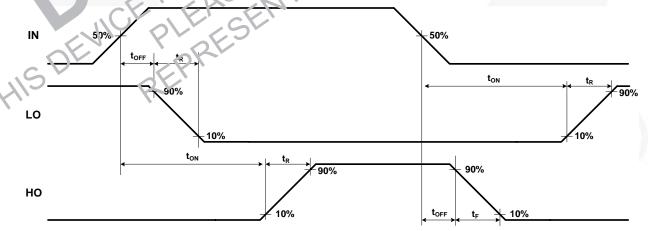
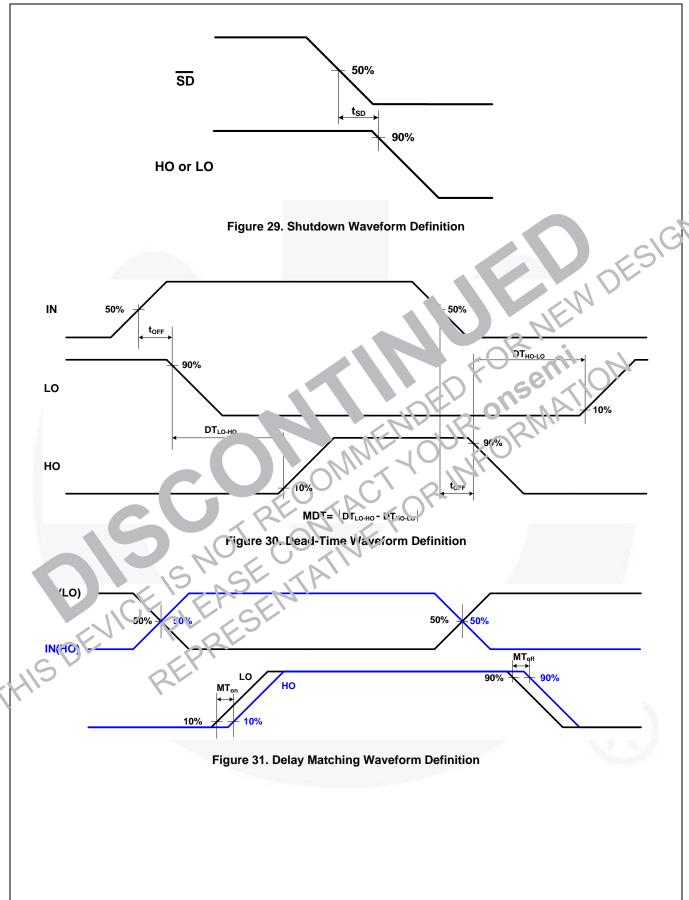


Figure 28. Switching Time Waveform Definition



### **Mechanical Dimensions**

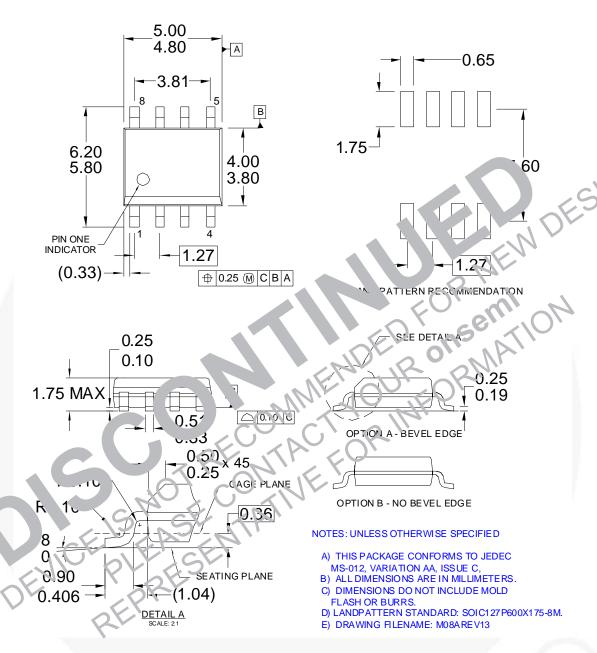


Figure 32. 8-Lead Small Outline Package (SOP)

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